

Vishay General Semiconductor

# **Dual Common Cathode High Voltage Schottky Rectifier**

# PIN 1 PIN 2 CASE

PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	2 x 5.0 A				
$V_{RRM}$	90 V, 100 V				
I <sub>FSM</sub>	120 A				
V <sub>F</sub>	0.75 V				
T <sub>J</sub> max.	150 °C				
Package	TO-220AB				
Circuit configurations	Common cathode				

### **FEATURES**

- Trench MOS Schottky technology
- · Lower power losses, high efficiency
- · Low forward voltage drop
- · High forward surge capability
- High frequency operation
- Solder bath temperature 275 °C maximum, 10 s, per JESD 22-B106
- Material categorization: for definitions of compliance please see <a href="https://www.vishay.com/doc?99912"><u>www.vishay.com/doc?99912</u></a>

### TYPICAL APPLICATIONS

For use in high frequency rectifier of switching mode power supplies, freewheeling diodes, DC/DC converters or polarity protection application

### **MECHANICAL DATA**

Case: TO-220AB

Molding compound meets UL 94 V-0 flammability rating Base P/N-E3 - RoHS-compliant, commercial grade

Terminals: matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix meets JESD 201 class 1A whisker test

Polarity: as marked

Mounting Torque: 10 in-lbs max.

MAXIMUM RATINGS (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER			MBR1090CT	MBR10100CT	UNIT		
Max. repetitive peak reverse voltage			90	100	V		
Working peak reverse voltage			90	100	V		
Max. DC blocking voltage			90	100	V		
Max. average forward rectified current at T <sub>C</sub> = 105 °C	total device	I <sub>F(AV)</sub>	10		А		
	per diode		5.0				
Peak forward surge current 8.3 ms single half sine-wave superimposed on rated load per diode			120		Α		
Non-repetitive avalanche energy at T <sub>J</sub> = 25 °C, L = 60 mH per diode			60		mJ		
Peak repetitive reverse current at $t_p$ = 2 $\mu$ s, 1 kHz, $T_J$ = 38 °C $\pm$ 2 °C per diode		I <sub>RRM</sub>	0.5		Α		
Voltage rate of change (rated V <sub>R</sub> )			10 000		V/µs		
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>STG</sub>	- 65 to + 150		°C		

<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>C</sub> = 25 °C unless otherwise noted)							
PARAMETER	TEST CONDITIONS		SYMBOL	MBR1090CT	MBR10100CT	UNIT	
Maximum instantaneous forward voltage per diode	$I_F = 5.0 A$	T <sub>C</sub> = 125 °C	V <sub>F</sub> <sup>(1)</sup>	0.75		V	
	$I_F = 5.0 \text{ A}$	T <sub>C</sub> = 25 °C	<b>V</b> F ('')	0.	85	v	
Maximum reverse current per diode at working peak		T <sub>J</sub> = 25 °C	I <sub>R</sub> (2)		μA		
reverse voltage		T <sub>J</sub> = 100 °C	IR (-)	6	.0	mA	

### Notes

(1) Pulse test: 300 µs pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms



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THERMAL CHARACTERISTICS (T <sub>C</sub> = 25 °C unless otherwise noted)						
PARAMETER	SYMBOL	MBR1090CT MBR10100CT				
Typical thermal resistance per diode	$R_{ heta JC}$	4.4		°C/W		

ORDERING INFORMATION (Example)						
PACKAGE	PREFERRED P/N	UNIT WEIGHT (g)	PACKAGE CODE	BASE QUANTITY	DELIVERY MODE	
TO-220AB	MBR10100CT-E3/4W	1.87	4W	50/tube	Tube	

### **RATINGS AND CHARACTERISTICS CURVES** (T<sub>A</sub> = 25 °C unless otherwise noted)

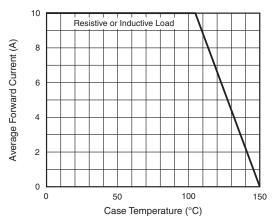


Fig. 1 - Forward Current Derating Curve

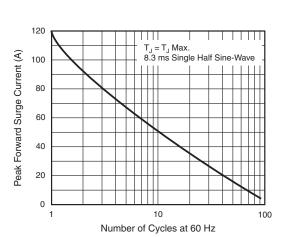


Fig. 2 - Maximum Non-Repetitive Peak Forward Surge Current Per Diode

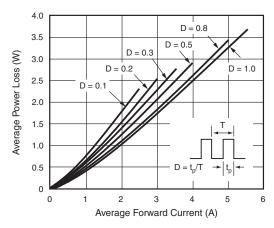


Fig. 3 - Forward Power Loss Characteristics Per Diode

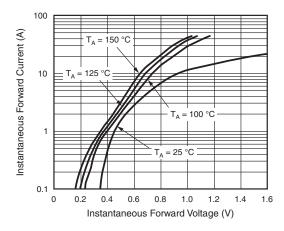


Fig. 4 - Typical Instantaneous Forward Characteristics Per Diode



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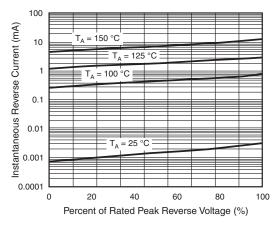


Fig. 5 - Typical Reverse Characteristics Per Diode

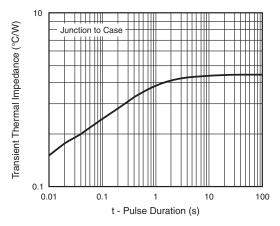


Fig. 7 - Typical Transient Thermal Impedance Per Diode

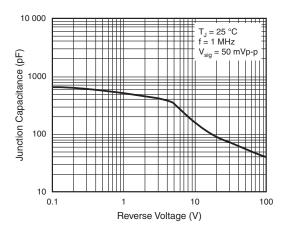


Fig. 6 - Typical Junction Capacitance Per Diode

### PACKAGE OUTLINE DIMENSIONS in inches (millimeters)

### TO-220AB 0.415 (10.54) 0.380 (9.65) 0.185 (4.70) 0.161 (4.08) 0.175 (4.44) 0.139 (3.53) 0.055 (1.39) 0.113 (2.87) 0.045 (1.14) 0.103 (2.62) 0.603 (15.32) 0.635 (16.13) 0.573 (14.55) 0.625 (15.87) PIN 0.350 (8.89) 2 0.330 (8.38) 0.160 (4.06) 1.148 (29.16) 0.140 (3.56) 1.118 (28.40) 0.110 (2.79) 0.100 (2.54) 0.057 (1.45) 0.045 (1.14) 0.560 (14.22) 0.530 (13.46) 0.035 (0.90) 0.028 (0.70) 0.104 (2.65) 0.022 (0.56) 0.205 (5.20) 0.096 (2.45) 0.014 (0.36) 0.195 (4.95)



# MBR1090CT-E3, MBR10100CT-E3

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